

# BRCs060N04SZCQ

Rev.A Sep.-2022

## / Descriptions

PDFN5×6 N

N-Channel MOSFET in a PDFN5×6 Plastic Package.

## / Features

AEC-Q101

Low  $R_{DS(ON)}$  to minimize conductive loss; low Gate Charge for fast switching; Low Thermal resistance; Qualified to AEC-Q101 Standards for High Reliability; HF Product.

## / Applications

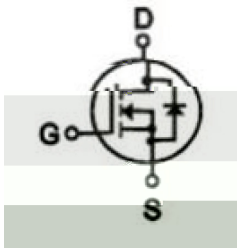
MB/NB/UMPC/VGA

Buck

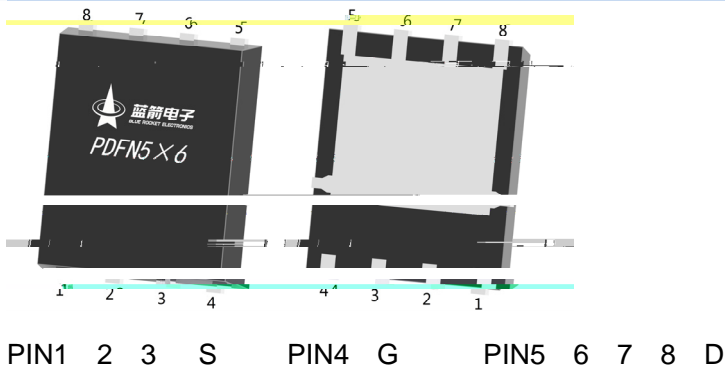
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Battery Management, High Frequency Point-of-Load Synchronous Buck Converter for MB/NB/UMPC/VGA, Networking DC-DC Power System, Load Switch, Meet the stringent requirements of automotive applications.

## / Equivalent Circuit



## / Pinning



Pin	极性
1	S
2	S
3	S
4	G
5	D
6	D
7	D
8	D

## / Marking

See Marking Instructions.

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Parameter	Symbol	Rating	Unit
Drain-Source Voltage	$V_{DS}$	40	V
Drain Current - Continuous	$I_D$	30	A
Drain Current – Pulsed	$I_{DM}$	110	A
Gate-Source Voltage	$V_{GS}$	$\pm 20V$	V
Power Dissipation	$P_D(T_c=25^\circ C)$	36.5	W
Single Pulse Avalanche Energy(L=0.5mH)	$E_{AS}$	78.5	mJ
Avalanche Current(L=0.5mH)	$I_{AS}$	15	A
Junction and Storage Temperature Range	$T_j, T_{stg}$	-55 to 150	
Thermal resistance, junction - ambient	t = 10s	$R_{JA}$	/ W
	Steady-State		
Thermal resistance, junction - case	Steady-State	$R_{JC}$	3.4

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	$BV_{DSS}$	$I_D=250\mu A, V_{GS}=0V$	40	46		V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=40V, V_{GS}=0V$			1	$\mu A$
Gate-Body leakage current	$I_{GSS}$	$V_{DS}=0V, V_{GS}=\pm 20V$			$\pm 100$	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.0	1.6	2.5	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=10A$		5.6	6	m
		$V_{GS}=4.5V, I_D=10A$		7.8	9	
Diode Forward Voltage	$V_{SD}$	$I_S=1A, V_{GS}=0V$			1.2	V

Input Capacitance

$C_{iss}$

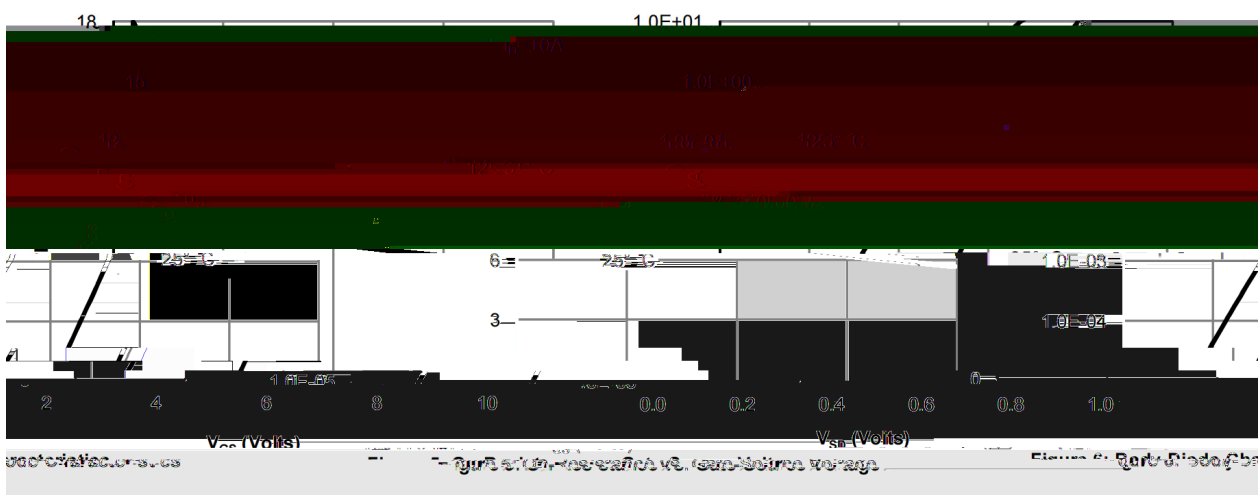
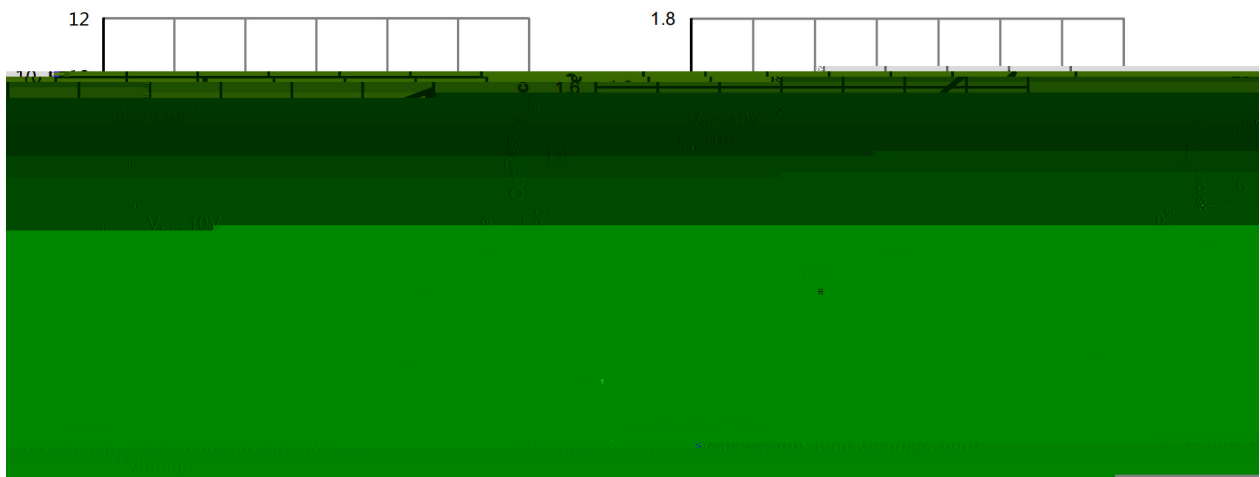
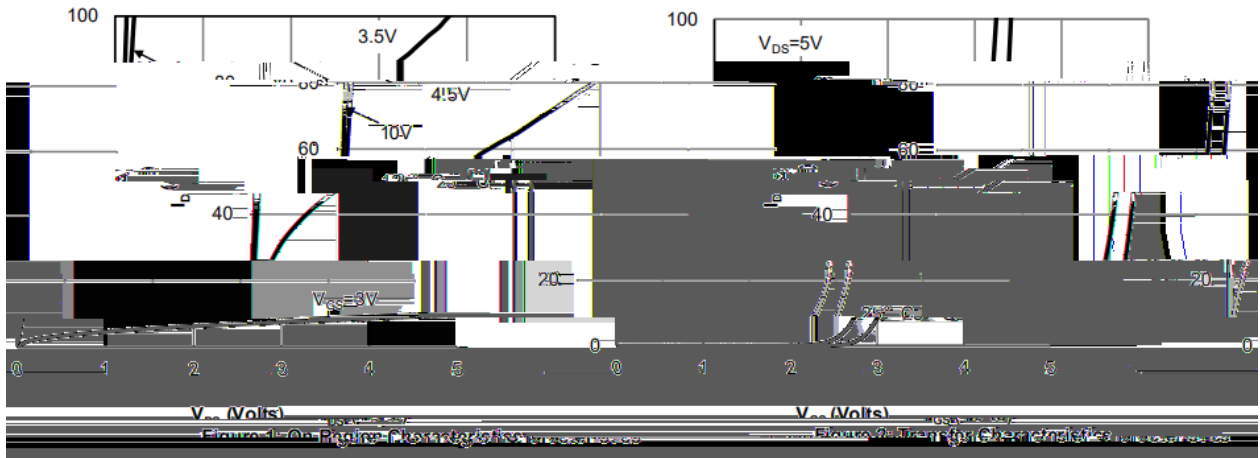
$V_{DS}=25V$

$V_{DSS} 100 nA 6(V) T J 7.0958 0 0 15$

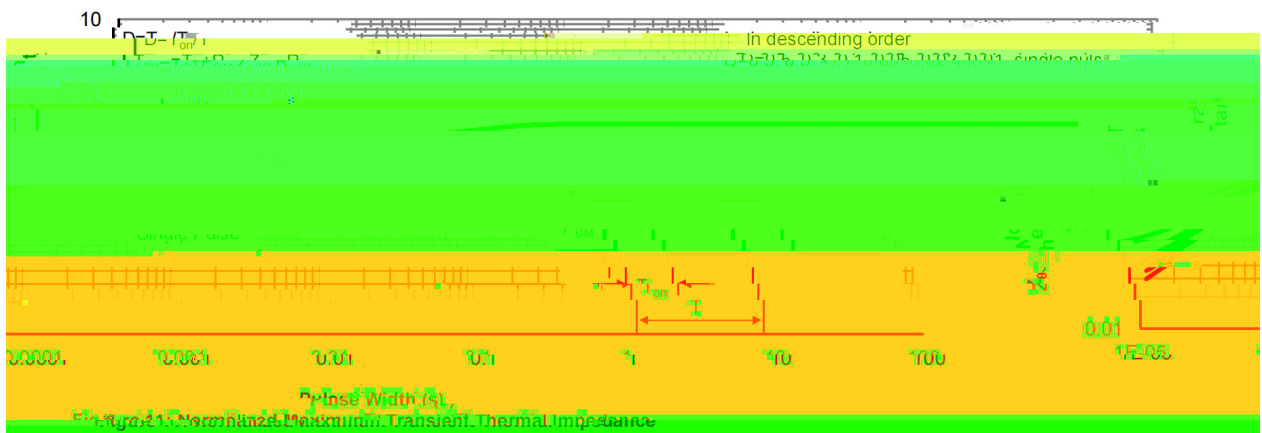
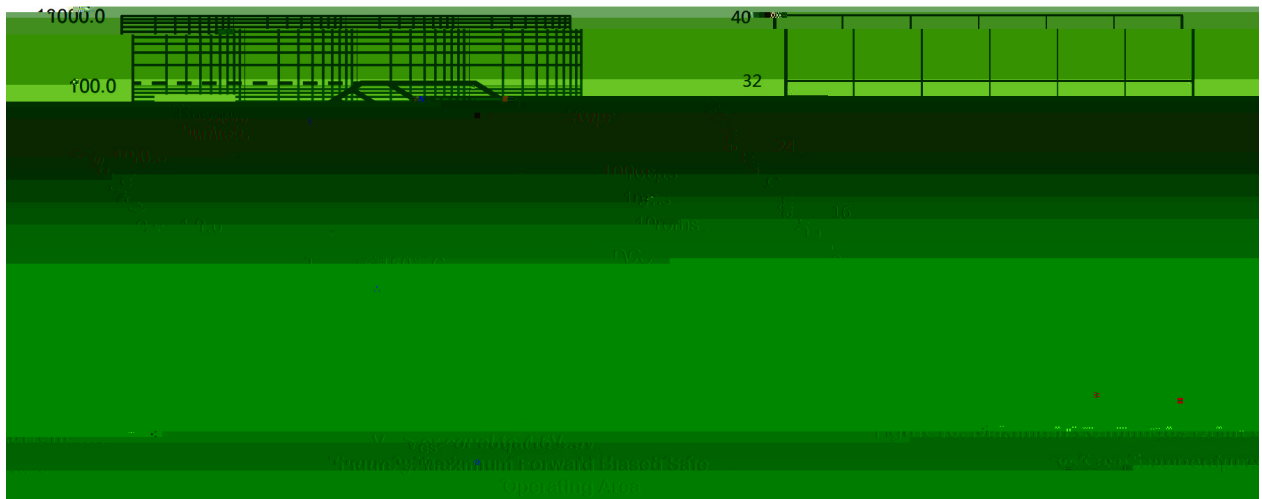
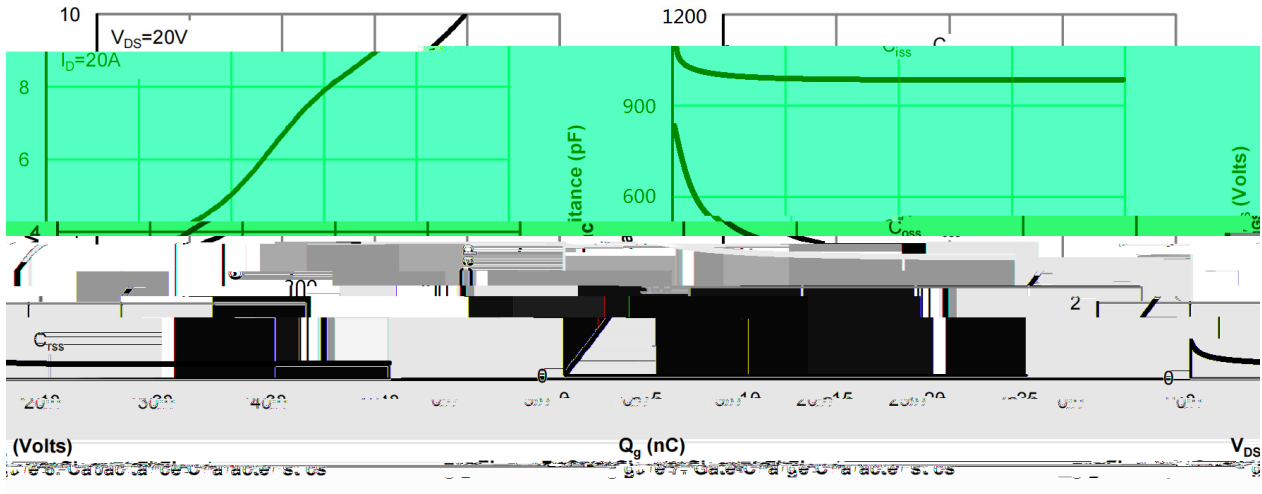
**/ Electrical Characteristics(Ta=25 )**

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=10V$ $V_{DS}=20V$ $R_L=1.0$ $R_{GEN}=3$		7.5		ns
Turn-On Rise Time	$t_r$			2		
Turn-Off Delay Time	$t_{d(off)}$			23		
Turn-Off Fall Time	$t_f$			3		

/ Electrical Characteristic Curve

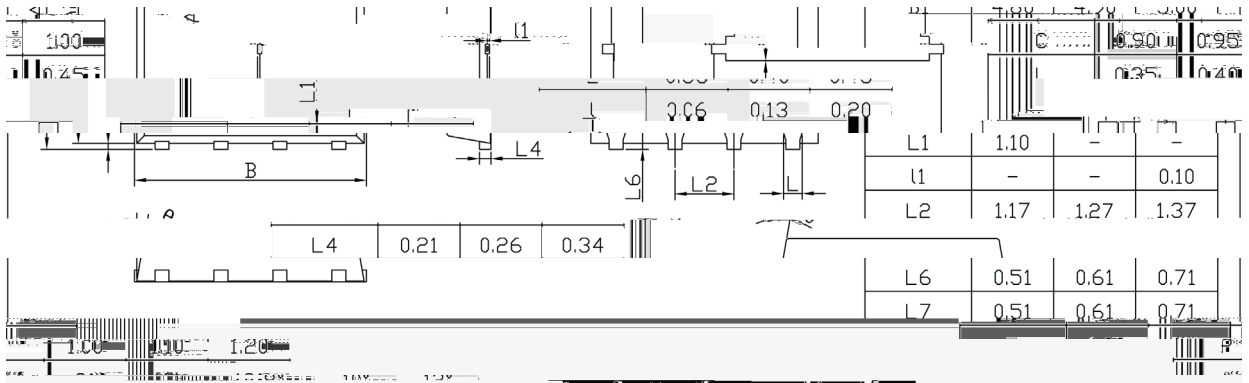


/ Electrical Characteristic Curve



**/ Package Dimensions**

PDEN15 X6 Unit:mm





**/ Marking Instructions**



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060N04S

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Note

BR            Company Code

Q:            Automobile halogen-free product Code

060N04S    Product Type

\*\*\*\*:        Lot No. Code, code change with Lot No

( ) / Temperature Profile for IR Reflow Soldering(Pb-Free)


Note:

- 1      150 200      60 120sec;      1.Preheating:150~200 , Time:60~120sec.
- 2      255±5      5±